

# The absence of super uid response in ac and bc-plane optical conductivities of optim ally-doped $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$ single crystals in the surface region

J. J. Tu,<sup>1</sup> C. C. Homes,<sup>2</sup> L. H. Greene,<sup>3</sup> G. D. Gu,<sup>2</sup> and M. Strongin<sup>2</sup>

<sup>1</sup>Department of Physics, City College of the City University of New York, New York, New York 10031

<sup>2</sup>Department of Physics, Brookhaven National Laboratory, Upton, New York 11973

<sup>3</sup>Department of Physics and the Fredrick Seitz Materials Research Laboratory, University of Illinois at Urbana-Champaign, Urbana, Illinois 61801

(Dated: April 14, 2024)

The optical properties of optim ally-doped  $\text{Bi}_2\text{Sr}_2\text{CaCu}_2\text{O}_{8+x}$  ( $\text{Bi}_2212$ ) have been measured normal to the edge planes [ac plane, bc plane, and (110) plane], for light polarized parallel to nodal and antinodal (gap) directions, respectively. While the super uid contribution can be obtained from the optical conductivities in the (110)-plane, it is unobservable in the ac and bc-planes. This apparent asymmetry implies that the edge region of high- $T_c$  cuprates is unusual and further supports a d-wave symmetry of the superconducting order parameter.

PACS numbers: 74.25.Gz, 74.72.Hs, 74.25.Nf

Understanding the microscopic mechanism of high-temperature (high- $T_c$ ) superconductors remains one of the fundamental challenges of condensed matter physics. Phase-sensitive techniques [1, 2, 3, 4, 5] imply a d-wave symmetry of the superconducting order parameter. Angle-resolved photoemission (ARPES) results in  $\text{Bi}_2212$  [6] clearly show an anisotropic energy gap. However, ab-plane optical conductivity measurements on the same material do not show large anisotropies with light (electric field vector) polarized parallel to a-axis, b-axis, or antinodal directions [7, 8] even below  $T_c$ . This can be understood since ARPES is a k-dependent measurement, whereas the optical conductivity is averaged over the Fermi surface. In general, one would expect the same kind of optical results for the edge planes [the ac-plane, bc-plane, and (110)-plane]. These edge regions of high- $T_c$  superconductors were studied extensively by tunneling experiments on  $\text{YBa}_2\text{Cu}_3\text{O}_{6+x}$  [4, 9, 10, 11, 12, 13] and more recently on  $\text{Bi}_2212$  by Greene and co-workers [14]. One particularly intriguing feature is the zero bias conductance peak (ZBCP) observed on the ac or bc-faces, coupled with the absence of a gap feature when tunneling into ab-plane. This is contrasted with the observation of a weaker ZBCP when tunneling into the (110)-plane, with the appearance of a superconducting gap [14]. We emphasize that for this work we take the crystallographic a and b axis along the Cu-Cu bonds as the nodal direction, whereas the [110] direction (the antinodal or gap-maximum direction) is along the Cu-O bonds.

In the superconducting state a particle bound state forms at the Fermi surface when the node of a d-wave order parameter is normal to a reflecting surface [15], such as the ac and bc-faces of  $\text{Bi}_2212$ . Particles reflecting from such surfaces experience a change in the sign of the order parameter along their classical trajectory and subsequently undergo Andreev reflection. Constructive interference between incident and Andreev-reflected particles leads to the formation of bound states con-

ned to the surface. These bound states will produce a ZBCP in a tunneling spectrum [16, 17, 18]. Andreev scattering causes strong pair breaking, which leaves a surface region depleted of super uid. The motivation of this study is to examine systematically these surface regions in  $\text{Bi}_2212$  by measuring the optical conductivities. The question is whether the picture used to explain the tunneling measurements, which probe a surface region of the order of  $\sim 10$  nm, can be used to describe the wider surface region probed by infrared radiation, which is typically  $\sim 100$  nm.

In this Letter, we report characteristically different behavior observed in the ac and bc-plane conductivities of optim ally doped  $\text{Bi}_2212$  as compared to the (110)-plane conductivities below  $T_c$ . While the super uid contribution can be measured in the optical conductivities in the (110)-plane, it is much smaller in the ac and bc-plane. This apparent asymmetry implies that the edge region in high- $T_c$  d-wave superconductors has unusual properties that are different from the bulk.

The ab-plane optical conductivity of optim ally-doped  $\text{Bi}_2212$  has been measured extensively [7, 8, 19, 20, 21]. However, because of the large c-axis dimension required to carry out optical measurements on the ac, bc and (110) faces, only one brief study was previously reported [22]. For this study, large optim ally-doped  $\text{Bi}_2212$  single crystals are grown using the traveling-surface-coating-zone (TSFZ) method. The typical size of these crystals for the edge experiments is  $5 \times 3 \times 1$  mm<sup>3</sup> along the three principle crystallographic axes. Cleaved (001) surfaces are used for the ab-plane measurements. However, to study the edge regions, polished (100), (010) and (110) surfaces are required. Considerable care has been taken during polishing due to the mica-like nature of  $\text{Bi}_2212$ . Polishing has been done by hand, and always along the planar direction. A final polish with 0.1  $\mu$ m diamond

allows optical surface quality to be achieved. The surface quality of our polished samples should be com-

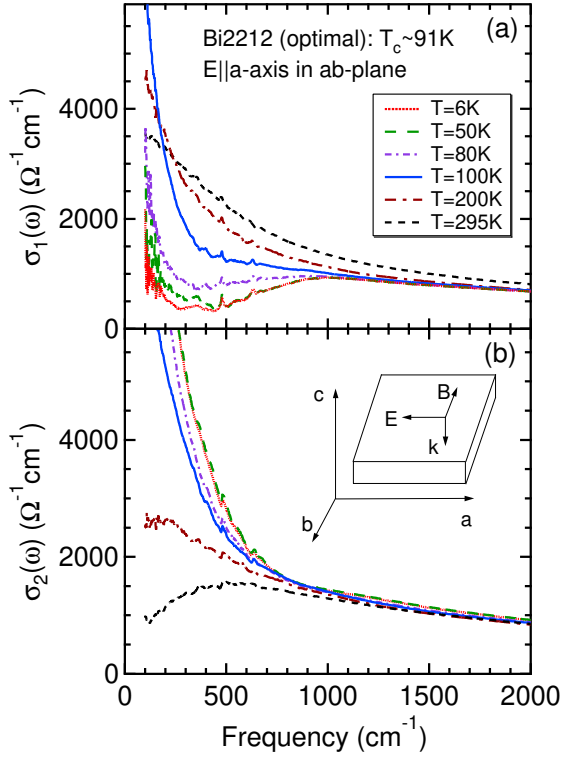


FIG. 1: The ab-plane conductivity data of an optimally-doped Bi2212 single crystal for E || a. (a) Temperature-dependent  $\sigma_1$ ; (b) temperature-dependent  $\sigma_2$ . Inset: the experimental configuration.

comparable to that of the samples used in the tunneling experiments on Bi2212 [14], which have been found to have a surface roughness of  $\sim 80 \text{ \AA}$  measured by AFM. The Bi2212 crystals are mounted on an optically-black cone, and the temperature-dependent polarized reflectance is measured in a near-normal-incidence arrangement from 50 to over 16,000  $\text{cm}^{-1}$  on a Bruker IFS 66v/S. The absolute reflectivity is determined by evaporating a gold film in situ over the sample [23]. This comparison to the gold reflectivity provides an absolute reflectivity scale. The optical conductivities are then determined from a Kramers-Kronig analysis.

The temperature-dependent ab-plane conductivity data is shown in Fig. 1 for a single-crystal Bi2212 sample with for light polarized along the a axis (E || a). In agreement with the previous results [7], there is only a weak dependence of the conductivity on the direction of the polarization within the ab-plane. However, strong phonon anisotropy has been observed in our ab-plane conductivity measurements [8, 24]. The superfluid response is observed in the ab-plane conductivities below  $T_c$ , as  $\sigma_1$  decreases with temperature according to the Ferrell-Glover-Tinkham sum rule accompanied by a simultaneous increase in  $\sigma_2$ . The ab-plane data is presented here as a reference to show the large difference from the edge plane data presented in the next figure.

The temperature-dependent ac-plane conductivity

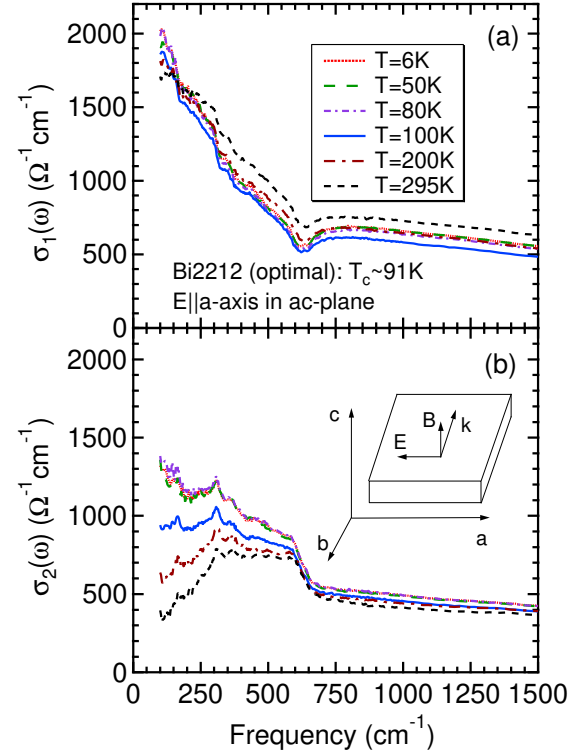


FIG. 2: The ac-plane conductivity data of an optimally-doped Bi2212 single crystal for E || a. No superfluid response is observed in either  $\sigma_1$  or  $\sigma_2$ . (a) Temperature-dependent  $\sigma_1$ ; (b) temperature-dependent  $\sigma_2$ . Inset: the experimental configuration.

data is shown in Fig. 2 for a single-crystal Bi2212 sample for E || a. The temperature-dependent conductivity data measured on a (110)-plane is shown in Fig. 3 for E || k [110]. The main point of comparing the ac-plane and the (110)-plane conductivity, is that while the superfluid contribution to optical conductivity is observed in the (110)-plane as shown in Fig. 3, it is unobservable in ac-plane as given in Fig. 2. In both cases,  $\sigma_1$  at room temperature is similar, but significantly lower than the ab-plane value. However, it can be seen that as the temperature is lowered below  $T_c$ , which is  $\sim 91 \text{ K}$  for these optimally-doped samples, the behavior of the (110)-plane conductivity data is much closer to the ab-plane data, showing the characteristic decrease of  $\sigma_1$  as normal carriers start to condense into superfluid which leads to a significant increase of  $\sigma_2$  below  $T_c$ . The behavior of the ac-plane conductivity around and below  $T_c$  is very different. As the temperature changed from 100 to 80 K, both  $\sigma_1$  and  $\sigma_2$  show a significant increase, particularly in  $\sigma_2$  below 500  $\text{cm}^{-1}$  [Fig. 2(b)]. As the temperature is lowered further, no noticeable changes are observed in  $\sigma_1$  or  $\sigma_2$ . Similar results are obtained for the bc-plane conductivity as compared to the ac-plane conductivity.

The essence of our results is the difference between Fig. 2 and Fig. 3, where the conductivities in the surface regions are compared for a surface with a normal along

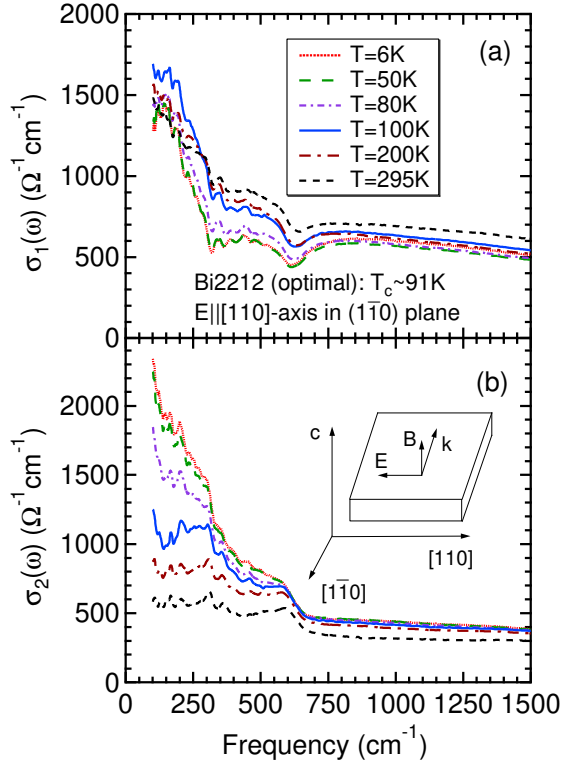


FIG. 3: The (110)-plane conductivity data of an optimally-doped Bi2212 single crystal for  $E \parallel [110]$ . In contrast to  $\sigma_1$  and  $\sigma_2$  in this case. (a) Temperature-dependent  $\sigma_1$ ; (b) temperature-dependent  $\sigma_2$ . Inset: the experimental configuration.

a nodal direction and a surface with a normal along an anti-nodal direction. It immediately shows that while the superfluid contribution to optical conductivity can be observed in the surface region of the (110)-plane, it is unobservable in the surface region of the  $ac$  or  $bc$  planes. This apparent asymmetry implies that the surface region in the high- $T_c$  d-wave superconductors has unusual properties that are different from the bulk [25].

The comparison with the  $ab$ -plane conductivities shows that the conductivities in these edge regions at room temperature are reduced by about a factor of two, and this is no doubt due to the polishing process. To further understand the role of disorder induced by the polishing process, we have added a set of data to show that with a coarser polishing finish (1  $\mu$ m diamond 1 $\mu$ m) the conductivity of the  $bc$ -plane in the normal state is even more drastically reduced, as shown in Fig. 4. There is a large spectral feature at 627  $\text{cm}^{-1}$  that appears as an anti-resonance dip in  $\sigma_1$ . This anti-resonance dip is also observed in  $\sigma_1$  of the better-polished surfaces as shown in Fig. 2(a) and Fig. 3(a), albeit with less spectral weight, but not in the  $ab$ -plane conductivity data. It is due to  $ab$ -plane carriers coupling to a  $c$ -axis LO phonon [24], but not caused by direct absorption of  $c$ -axis TO phonons [26]. In the inset of Fig. 4(a), room temperature reflectance data is given with the  $E \parallel b$  and  $E \parallel c$  on this

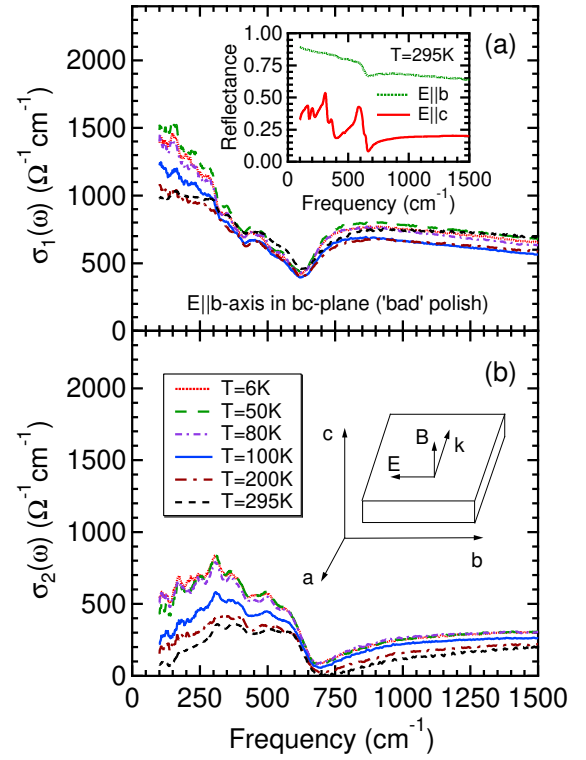


FIG. 4: The  $bc$ -plane conductivity data of an optimally doped Bi2212 single crystal that has a coarser surface finish for  $E \parallel b$ . No superfluid response is observed in either  $\sigma_1$  or  $\sigma_2$ . (a) Temperature-dependent  $\sigma_1$ . Inset: the room-temperature reflectance data for  $E \parallel b$  and  $E \parallel c$ , respectively. (b) Temperature-dependent  $\sigma_2$ . Inset: the experimental configuration.

$bc$  face. Features associated with  $c$ -axis TO phonons are absent in the  $E$  parallel to  $b$ -axis spectrum. We therefore conclude that there is no significant contamination by  $c$ -axis phonons in the conductivity data with  $E \parallel b$ . This indicates that even with this coarser polishing finish, the planar structure of the Bi2212 is preserved in these polished surface regions. Still, with coarser polishing there is little evidence of superfluid response in  $\sigma_1$  or  $\sigma_2$  similar to what is observed on better polished  $ac$  and  $bc$  surfaces.

The surprising aspect of our results is the characteristically different behavior of the optical conductivities in the interface regions of a surface with the normal along a nodal direction, compared to that of a surface with the normal along an anti-nodal (gap) direction. While the superfluid contribution to optical conductivity can be measured on the (110)-plane, it is unobservable on the  $ac$  or  $bc$  planes. The superconductivity as probed by infrared techniques may behave in a way similar to what Greene and co-workers have found in their tunneling experiments [14]. In the surface region where the node of a d-wave order parameter is normal to a reflecting surface like the  $ac$  and  $bc$  faces of a high- $T_c$  superconductor, Andreev scattering causes strong pair breaking which leaves a surface region depleted of superfluid. This may explain

why no superfluid response is observed in ac and bc-plane conductivity. The situation is different for the surface region for which the normal is an anti-nodal direction. Ideally, there should be no Andreev scattering because the superconducting pairs do not suffer a change of sign in the order parameter under a reflection on this interface. This explains why a superfluid response is observed in the (110)-plane conductivity, albeit with less magnitude compared to ab-plane data, and there is a superconducting gap when tunneling on (110)-plane accompanied by a less pronounced ZBCP.

The small jump in  $\rho_1$  and  $\rho_2$  from 100 to 80 K deserves some more discussion. A careful study reveals that the increase almost exclusively occurs within a few degrees of  $T_c$ . We speculate that this jump is related to the formation of Andreev bound states in the surface region of ac and bc plane as a result of, e.g. a reduction in scattering rate when bound states are formed below  $T_c$ . The Andreev bound state should deplete the superfluid to a depth of order the coherence length  $\xi_0 \approx 100 \text{ \AA}$ . The classical skin depth is defined as  $\delta = c/2\pi f$ , which is of the order of microns and much greater than the mean-free path, so that since  $\xi_0 \ll \delta$  the infrared should still probe the superfluid in the bulk. This is seemingly at odds with the observation of no further change in  $\rho_1$  and  $\rho_2$  for  $T < T_c$ . Within the BCS theory,  $\xi_0$  can be defined in terms of the Fermi velocity  $v_F$  and the energy gap  $\Delta$ ,  $\xi_0 = \hbar v_F / \Delta$ . However, the energy gap is thought to have a momentum dependence, thus  $\xi_0(\mathbf{k})$ . If  $\xi_0(\mathbf{k}) \neq 0$  in the nodal direction, then  $\xi_0(\mathbf{k})$  may become quite large, i.e.  $\xi_0(\mathbf{k}) \gg \xi_0$ , which would suggest for certain geometries the influence of the Andreev bound state might extend over a larger region than previously thought [27].

The role of disorder induced by the polishing process also deserves some further considerations. This kind of problem seems to be reminiscent to the "two-length scale" problem in X-ray scattering [28, 29]. For example, in the case of  $\text{UO}_2$  [30] and  $\text{SrTiO}_3$  [31], it is found that mechanical processing causes an increase in dislocation density in the surface region that can be as deep as 500 nm. However, we do not think that random disorder can explain the asymmetry we have observed in our optical measurements nor the asymmetry observed in the tunneling experiments. Of course, if the polishing process caused different amounts of damage on two types of surfaces this could happen, but the data shows there are no large changes in the normal-state conductivity for the two cases. This issue of the extent of the depletion region remains to be understood.

In conclusion, we have observed characteristically different behavior in the ac and bc-plane optical conductivities of optimally-doped  $\text{Bi}_{2212}$  single crystals, as compared to the (110)-plane conductivity below  $T_c$ . Our observation implies that optical measurements are also

sensitive to the d-wave nature of the superconducting order parameter in high- $T_c$  cuprates.

We would like to thank D. N. Basov, A. V. Chubukov, V. J. Emery, P. D. Johnson, A. M. Illis, T. T. Imusk and T. Valla for helpful discussions. This work was supported by the Department of Energy (DOE) under Contract No. DE-AC02-98CH10886. LHG acknowledges support from DOE under Contract No. DE-FG02-ER9645439, through the Frederick Seitz Materials Research Laboratory.

---

Electronic address: homes@bnlgov

- [1] C. C. Tsuei et al, Phys. Rev. Lett. 73, 593 (1994).
- [2] D. A. Wollman, D. J. Van Harlingen, J. Giapintzakis, and D. M. Ginsberg, Phys. Rev. Lett. 74, 797 (1995).
- [3] D. J. Van Harlingen, Rev. Mod. Phys. 67, 515 (1995).
- [4] M. Covington et al, Phys. Rev. Lett. 79, 277 (1997).
- [5] M. Sutherland et al, Phys. Rev. B 67, 174520 (2003).
- [6] T. Valla et al, Science 285, 2110 (1999).
- [7] M. A. Quijada et al, Phys. Rev. B 60, 14917 (1999).
- [8] J. J. Tu et al, Phys. Rev. B 66, 144514 (2002).
- [9] J. Geerk, X. X. Xi, and G. Linker, Z. Phys. B 73, 329 (1988).
- [10] J. Lesueur, L. H. Greene, W. L. Feldmann, and A. Inam, Physica C 191, 325 (1992).
- [11] J. Y. T. Wei, N.-C. Yeh, D. Garrigus, and M. Strassik, Phys. Rev. Lett. 81, 2542 (1998).
- [12] L. Al et al, Phys. Rev. B 58, 11197 (1998).
- [13] R. Knapke and G. Deutscher, Phys. Rev. Lett. 83, 4634 (1999).
- [14] H. Aubin, L. H. Greene, S. Jian, and D. G. Hinks, Phys. Rev. Lett. 89, 177001 (2002).
- [15] C. R. Hu, Phys. Rev. Lett. 72, 1526 (1994).
- [16] Y. Tanaka and S. Kashiwaya, Phys. Rev. Lett. 74, 3451 (1995).
- [17] M. Fogelstrom, D. Rainer, and J. A. Sauls, Phys. Rev. Lett. 79, 281 (1997).
- [18] A. Carrington et al, Phys. Rev. Lett. 86, 1074 (2001).
- [19] M. Reedyk et al, Phys. Rev. B 38, 11981 (1988).
- [20] A. V. Puchkov et al, Phys. Rev. Lett. 77, 3212 (1996).
- [21] N. L. Wang, A. W. McConnell, and B. P. Clayman, Phys. Rev. B 59, 576 (1999).
- [22] S. Tajima et al, Phys. Rev. B 48, 16164 (1993).
- [23] C. C. Homes, M. Reedyk, D. A. Candles, and T. T. Imusk, Appl. Opt. 32, 2972 (1993).
- [24] J. J. Tu, C. C. Homes, G. D. Gu, and M. Strongin, Physica B 316-317, 324 (2002).
- [25] K. A. Muller, cond-mat/0306643.
- [26] M. Reedyk and T. T. Imusk, Phys. Rev. Lett. 69, 2705 (1992).
- [27] S. Misra et al, Phys. Rev. B 66, 100510(R) (2002).
- [28] S. R. Andrews, J. Phys. C 19, 3721 (1986).
- [29] T. W. Ryan, R. J. Nelmes, R. A. Cowley, and A. G. Baud, Phys. Rev. Lett. 56, 2704 (1986).
- [30] G. M. Waston et al, Phys. Rev. B 53, 686 (1996).
- [31] R. Wang, Y. Zhu, and S. M. Shapiro, Phys. Rev. Lett. 80, 2370 (1998).